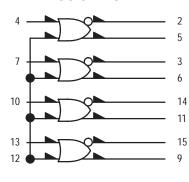
# **Quad OR/NOR Gate**

The MC10H101 is a quad 2–input OR/NOR gate with one input from each gate common to pin 12. This MECL 10H part is a functional/pinout duplication of the standard MECL 10K family part, with 100% improvement in propagation delay, and no increases in power–supply current.

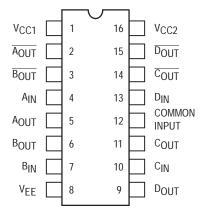
- Propagation Delay, 1.0 ns Typical
- Power Dissipation 25 mW/Gate (same as MECL 10K)
- Improved Noise Margin 150 mV (Over Operating Voltage and Temperature Range)
- Voltage Compensated
- MECL 10K–Compatible

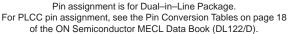


LOGIC DIAGRAM





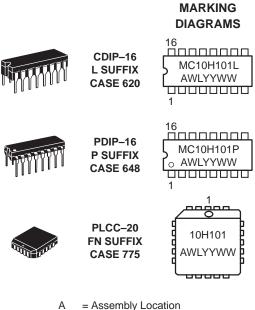






# **ON Semiconductor**

http://onsemi.com



A = Assembly Location WL = Wafer Lot YY = Year WW = Work Week

#### **ORDERING INFORMATION**

Device	Package	Shipping		
MC10H101L	CDIP-16	25 Units/Rail		
MC10H101P	PDIP-16	25 Units/Rail		
MC10H101FN	PLCC-20	46 Units/Rail		

#### MAXIMUM RATINGS

Symbol	Characteristic	Rating	Unit
VEE	Power Supply ( $V_{CC} = 0$ )	-8.0 to 0	Vdc
VI	Input Voltage (V <sub>CC</sub> = 0)	0 to V <sub>EE</sub>	Vdc
lout	Output Current – Continuous – Surge	50 100	mA
TA	Operating Temperature Range	0 to +75	°C
T <sub>stg</sub>	Storage Temperature Range – Plastic – Ceramic	–55 to +150 –55 to +165	°C ℃

### **ELECTRICAL CHARACTERISTICS** (V<sub>EE</sub> = $-5.2 \text{ V} \pm 5\%$ ) (See Note 1.)

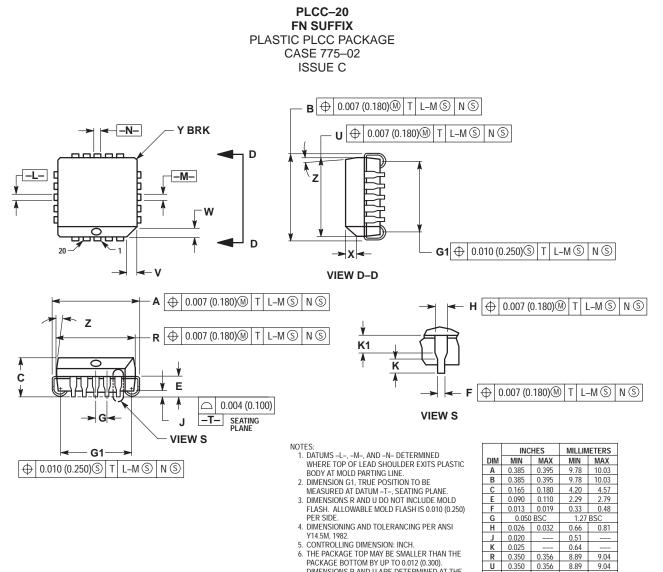
		<b>0</b> °		25°		75°		
Symbol	Characteristic	Min	Max	Min	Мах	Min	Max	Unit
ΙE	Power Supply Current	-	29	-	26	-	29	mA
linH	Input Current High (Pin 12 only)		425 850	-	265 535		265 535	μA
l <sub>inL</sub>	Input Current Low	0.5	-	0.5	-	0.3	-	μΑ
VOH	High Output Voltage	-1.02	-0.84	-0.98	-0.81	-0.92	-0.735	Vdc
VOL	Low Output Voltage	-1.95	-1.63	-1.95	-1.63	-1.95	-1.60	Vdc
VIH	High Input Voltage	-1.17	-0.84	-1.13	-0.81	-1.07	-0.735	Vdc
VIL	Low Input Voltage	-1.95	-1.48	-1.95	-1.48	-1.95	-1.45	Vdc

### AC PARAMETERS

tŗ	pd	Propagation Delay Pin 12 Only Exclude Pin 12	0.5 0.5	1.6 1.45	0.5 0.5	1.6 1.5	0.5 0.5	1.7 1.6	ns
1	t <sub>r</sub>	Rise Time	0.5	2.1	0.5	2.2	0.5	2.3	ns
1	tf	Fall Time	0.5	2.1	0.5	2.2	0.5	2.3	ns

 Each MECL 10H series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50–ohm resistor to –2.0 volts.

#### PACKAGE DIMENSIONS



6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

V 0.042

K1 0.040

Ζ

W 0.042 0.048

X 0.042 0.056 Y ---- 0.020

----2 °

G1 0.310 0.330

0.048

10

1.07

1.07

1.07

----2 °

7.88 8.38

1.02

1.21

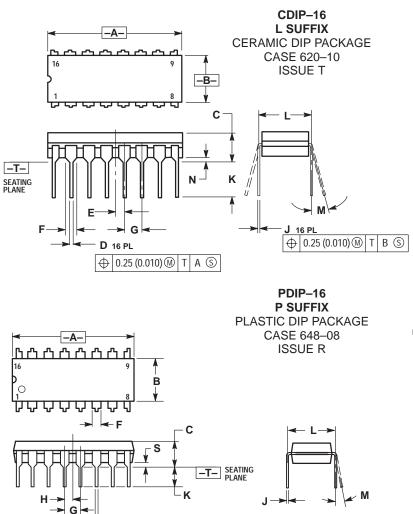
1.21

1.42

0.50

10 °

. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR 7. PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).



#### NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- CONTROLLING DIMENSION: INCH. DIMENSION L TO CENTER OF LEAD WHEN 3
- FORMED PARALLEL. DIMENSION F MAY NARROW TO 0.76 (0.030) 4

WHERE THE LEAD ENTERS THE CERAMIC BODY

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.020	0.39	0.50	
Ε	0.050 BSC		1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100 BSC		2.54 BSC		
Н	0.008	0.015	0.21	0.38	
К	0.125	0.170	3.18	4.31	
L	0.300 BSC		7.62 BSC		
М	0 °	15°	0 °	15 °	
Ν	0.020	0.040	0.51	1.01	

NOTES

- DIMENSIONING AND TOLERANCING PER ANSI 1
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 3

- DIMENSION B DOES NOT INCLUDE MOLD FLASH. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS		
DIM	MIN	MIN MAX		MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100 BSC		2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
К	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
М	0° 10°		0 °	10 °	
S	0.020	0.040	0.51	1.01	

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